

Application Number	Assigned 07510357.
Filing Date	October 5, 2004
First Named Inventor	Jing Hua Teng
Group Art Unit	
Examiner Name	
Attorney Docket	3136.ARTH.PT

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Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	To
		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)				
me		GB2358281	07-18-2001	Sharp Kabushiki Kaisha		
mm		GB2369492	05-29-2002	Kamelian Limited		

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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MAY 31 2005

Complete if Known

Application Number	10/510,357
Filing Date	October 5, 2004
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Group Art Unit	2812
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U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
nm		US-6,005,881	12-21-1999	Ikoma	
		US-5,915,165	06-22-1999	Sun et al.	
		US-5,886,370	03-23-1999	Sun et al.	
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nm		US-4,731,338	03-15-1988	Ralston et al.	
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Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T*
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